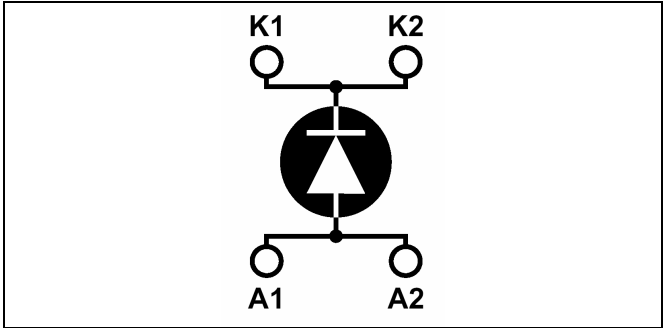


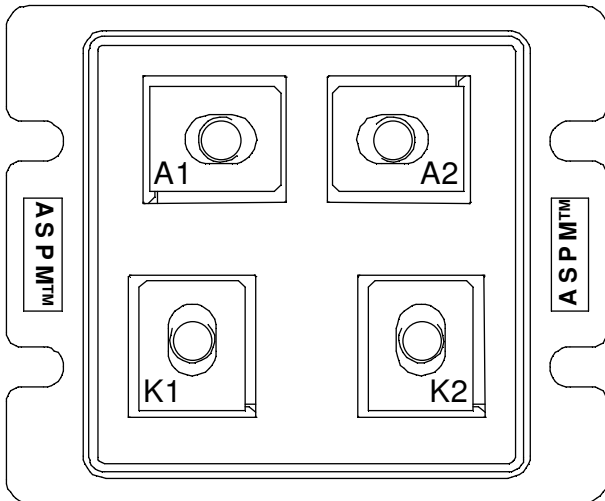
**Single diode
Power Module**

**$V_{CES} = 1200V$
 $I_C = 400A @ T_c = 80^\circ C$**



Application

- Anti-Parallel diode
 - Switchmode Power Supply
 - Inverters
- Snubber diode
- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers
- Electric vehicles



Features

- Ultra fast recovery times
- Soft recovery characteristics
- Very low stray inductance
- High blocking voltage
- High current
- Low leakage current

Benefits

- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit	
V_R	Maximum DC reverse Voltage	1200	V	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			
$I_{F(AV)}$	Maximum Average Forward Current	Duty cycle = 50%	$T_c = 25^\circ C$	A
			$T_c = 80^\circ C$	
$I_{F(RMS)}$	RMS Forward Current	750		
I_{FSM}	Non-Repetitive Forward Surge Current	$T_j = 25^\circ C$	5000	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

Electrical Characteristics

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V_F	Diode Forward Voltage	$I_F = 500\text{A}$			2.5	V
		$I_F = 1000\text{A}$		2.5		
		$I_F = 500\text{A}$	$T_j = 150^\circ\text{C}$			
I_{RM}	Maximum Reverse Leakage Current	$V_R = 1200\text{V}$	$T_j = 25^\circ\text{C}$		2500	μA
			$T_j = 125^\circ\text{C}$		5000	
C_T	Junction Capacitance	$V_R = 200\text{V}$		600		pF

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
t_{rr1}	Reverse Recovery Time	$I_F = 1\text{A}, V_R = 30\text{V}$ $di/dt = 15\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$	90		ns	
t_{rr2}		$I_F = 500\text{A}$ $V_R = 650\text{V}$	$T_j = 25^\circ\text{C}$	110			
t_{rr3}		$di/dt = 1000\text{A}/\mu\text{s}$	$T_j = 100^\circ\text{C}$	175			
t_{fr1}	Forward Recovery Time	$I_F = 500\text{A}$ $V_R = 650\text{V}$ $di/dt = 1000\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$	220		ns	
t_{fr2}			$T_j = 100^\circ\text{C}$	220			
I_{RRM1}	Reverse Recovery Current		$T_j = 25^\circ\text{C}$	70		A	
I_{RRM2}			$T_j = 100^\circ\text{C}$	120			
Q_{rr1}	Reverse Recovery Charge		$T_j = 25^\circ\text{C}$	10		μC	
Q_{rr2}			$T_j = 100^\circ\text{C}$	30			
V_{fr1}	Forward Recovery Voltage		$T_j = 25^\circ\text{C}$	26		V	
V_{fr2}			$T_j = 100^\circ\text{C}$	26			
$d_{IM/dt}$	Rate of Fall of Recovery Current		$T_j = 25^\circ\text{C}$		1200		A/ μs
			$T_j = 100^\circ\text{C}$		800		

Thermal and package characteristics

Symbol	Characteristic	Min	Typ	Max	Unit	
R_{thJC}	Junction to Case			0.08	$^\circ\text{C}/\text{W}$	
V_{ISOL}	RMS Isolation Voltage, any terminal to case $t = 1\text{ min}, I_{isol} < 1\text{mA}, 50/60\text{Hz}$	2500			V	
T_j	Operating junction temperature range	-40		150	$^\circ\text{C}$	
T_{STG}	Storage Temperature Range	-40		125		
T_C	Operating Case Temperature	-40		100		
Torque	Mounting torque	To heatsink	M5	2.5	3.5	N.m
		For terminals	M6	3	4	
Wt	Package Weight			250	g	

